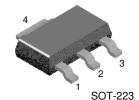


NZT6727

PNP General Purpose Amplifier

- This device is designed for general purpose medium power amplifiers and switches requiring collecor currents to 1.0A.
- Sourced from process 77.



1. Base 2. Collector 3. Emitter

Absolute Maximum Ratings* T_a=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	-40	V
V _{CBO}	Collector-Base Voltage	-50	V
V _{EBO}	Emitter-Base Voltage	-5.0	V
I _C	Collector Current - Continuous	-1.5	Α
T _J , T _{STG}	Operating and Storage Junction Temperature Range	- 55 ~ 150	°C

^{*} These ratings are limiting values above whitch the serviceability of any semiconductor device may be impaird.

- NOTES:

 1. These ratings are based on a maximum junction temperature of 150 degrees C.

 2. These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Characte	Off Characteristics				
V _{(BR)CEO}	Collector-Emitter Sustaining Voltage *	$I_C = -10 \text{mA}, I_B = 0$	-40		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_C = -1.0 \text{mA}, I_E = 0$	-50		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_E = -100 \mu A, I_C = 0$	-5.0		V
I _{CBO}	Collector Cutoff Current	$V_{CB} = -50V, I_{E} = 0$		-0.1	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = -5.0V, I_{C} = 0$		-0.1	μΑ
On Characteristics					
h _{FE}	DC Current Gain	I _C = -10mA, V _{CE} = -1.0V	55		
		$I_C = -100 \text{mA}, V_{CE} = -1.0$	60		
		$I_C = -1.0A, V_{CE} = -1.0V$	50	250	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = -1.0A, I_B = -100mA$		-0.5	V
V _{BE} (on)	Base-Emitter On Voltage	$I_C = -1.0A, V_{CE} = -1.0V$		-1.2	V
Small Signal Characteristics					
h _{fe}	Small Signal current Gain	$I_C = -50 \text{mA}, V_{CE} = -10 \text{V}, f = 20 \text{MHz}$	2.5	25	
C _{cb}	Collector-Base Capacitance	$V_{CB} = -10V, I_E = 0, f = 1.0MHz$		30	pF
	Width ≤ 300μs, Duty Cycle ≤ 1.0%	•			

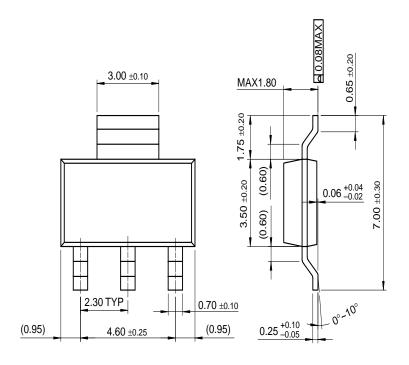
Thermal Characteristics $T_a=25$ °C unless otherwise noted

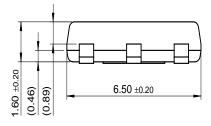
Symbol	Parameter	Max.	Units
P _D	Total Device Dissipation	1.0	W
	Derate above 25°C	8.0	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	125	°C/W

* Device mounted on FR-4PCB 36mm × 18mm × 1.5mm; mounting pad for the collector lead min. 6cm².

Package Dimensions

SOT-223





Dimensions in Millimeters

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